

Silicon Planar Zener Diodes

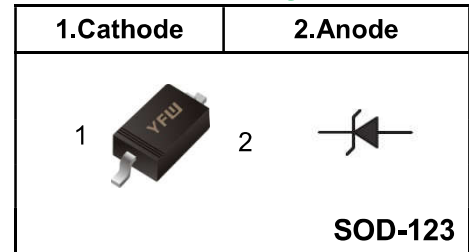
FEATURES

- ◆ Total power dissipation: Max. 500mW.
- ◆ Wide zener reverse voltage range 2.0 V to 75 V.
- ◆ Small plastic package suitable for surface mounted design.
- ◆ Tolerance approximately ± 2%.
- ◆ Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆ Case: SOD-123
- ◆ Terminals: Solderable per MIL-STD-750, Method 2026
- ◆ Approx. Weight: 15mg / 0.00048oz

Pinning



Absolute Maximum Ratings And Characteristics (Ta = 25 °C)

Parameter	Symbol	Value	Unit
Power Dissipation (Note 1)	P_D	500	mW
Forward Voltage (Note 2) at IF = 10 mA	V_F	0.9	V
Thermal Resistance from Junction to Ambient	R_{θJA}	340	°C/W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ +150	°C

(1) Thermal resistance from junction to ambient at P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper areas pads.

(2) Short duration test pulse used to minimize self-heating effect

(3) f = 1kHz

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Type	Marking	Zener Voltage Range ⁽¹⁾			I _{ZT} (mA)	Dynamic Impedance Z _{ZT} (at I _{ZT}) Max (Ω)	Reverse Current	
		V _{ZT} (at I _{ZT})					I _R	at V _R
		Min (V)	Nom (V)	Max (V)			Max (μA)	(V)
BZT52B2V0	2WY	1.96	2	2.04	5	100	120	0.5
BZT52B2V2	2WZ	2.16	2.2	2.24	5	100	120	0.7
BZT52B2V4	2WX	2.35	2.4	2.45	5	100	120	1
BZT52B2V7	2W1	2.65	2.7	2.75	5	110	120	1
BZT52B3V0	2W2	2.94	3	3.06	5	120	50	1
BZT52B3V3	2W3	3.23	3.3	3.37	5	130	20	1
BZT52B3V6	2W4	3.53	3.6	3.67	5	130	10	1
BZT52B3V9	2W5	3.82	3.9	3.98	5	130	5	1
BZT52B4V3	2W6	4.21	4.3	4.39	5	130	5	1
BZT52B4V7	2W7	4.61	4.7	4.79	5	130	2	1
BZT52B5V1	2W8	5	5.1	5.20	5	130	2	1.5
BZT52B5V6	2W9	5.49	5.6	5.71	5	80	1	2.5
BZT52B6V2	2WA	6.08	6.2	6.32	5	50	1	3
BZT52B6V8	2WB	6.66	6.8	6.94	5	30	0.5	3.5
BZT52B7V5	2WC	7.35	7.5	7.65	5	30	0.5	4
BZT52B8V2	2WD	8.04	8.2	8.36	5	30	0.5	5
BZT52B9V1	2WE	8.92	9.1	9.28	5	30	0.5	6
BZT52B10	2WF	9.8	10	10.2	5	30	0.1	7
BZT52B11	2WG	10.78	11	11.22	5	30	0.1	8
BZT52B12	2WH	11.76	12	12.24	5	35	0.1	9
BZT52B13	2WI	12.74	13	13.26	5	35	0.1	10
BZT52B15	2WJ	14.7	15	15.3	5	40	0.1	11
BZT52B16	2WK	15.68	16	16.32	5	40	0.1	12
BZT52B18	2WL	17.64	18	18.36	5	45	0.1	13
BZT52B20	2WM	19.6	20	20.4	5	50	0.1	15
BZT52B22	2WN	21.56	22	22.44	5	55	0.1	17
BZT52B24	2WO	23.52	24	24.48	5	60	0.1	19
BZT52B27	2WP	26.46	27	27.54	5	70	0.1	21
BZT52B30	2WQ	29.4	30	30.6	5	80	0.1	23
BZT52B33	2WR	32.34	33	33.66	5	80	0.1	25
BZT52B36	2WS	35.28	36	36.72	5	90	0.1	27
BZT52B39	2WT	38.22	39	39.78	2.5	100	2	30
BZT52B43	2WU	42.14	43	43.86	2.5	130	2	33
BZT52B47	2WV	46.06	47	47.94	2.5	150	2	36
BZT52B51	2WWW	49.98	51	52.02	2.5	180	1	39
BZT52B56	2X1	54.88	56	57.12	2.5	180	1	43
BZT52B62	2X2	60.76	62	63.24	2.5	200	0.2	47
BZT52B68	2X3	66.64	68	69.36	2.5	250	0.2	52
BZT52B75	2X4	73.5	75	76.5	2.5	300	0.2	57

(1) V_{ZT} is tested with pulses (20 ms)

Typical Characteristics

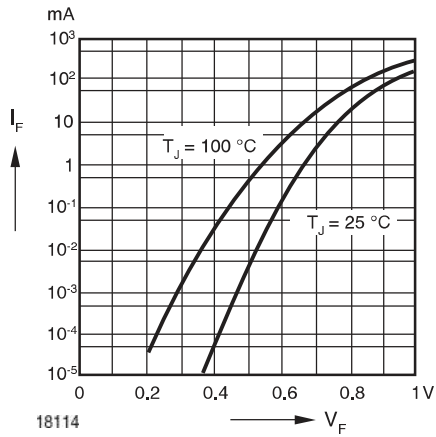


Fig. 1 - Forward characteristics

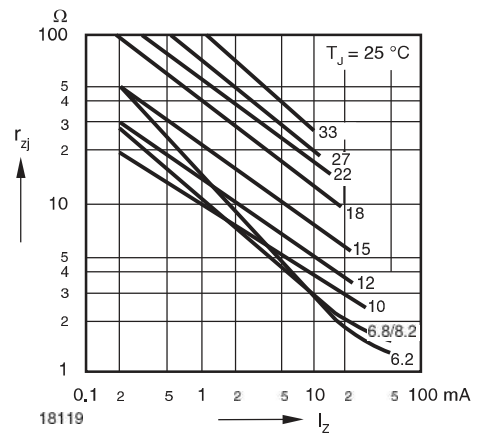


Fig. 4 - Dynamic Resistance vs. Zener Current

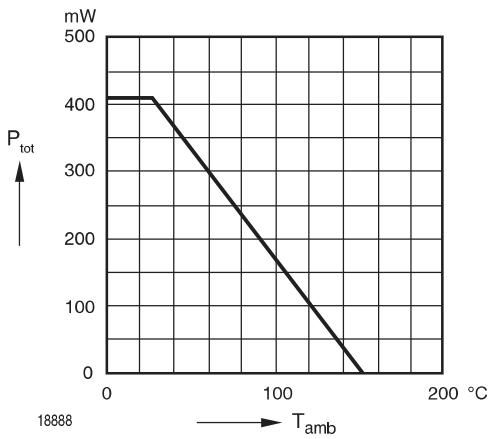


Fig. 2 - Admissible Power Dissipation vs. Ambient Temperature

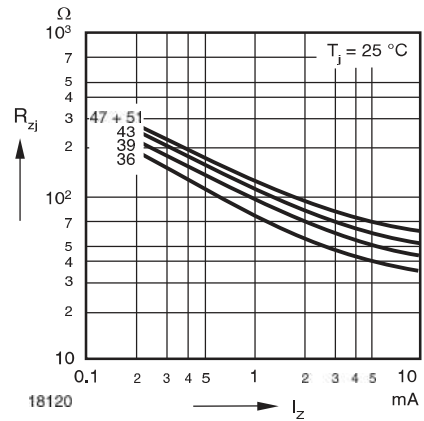


Fig. 5 - Dynamic Resistance vs. Zener Current

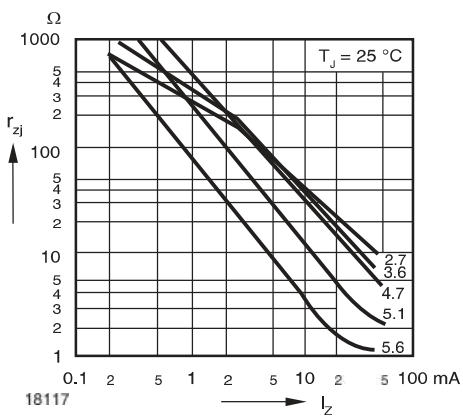


Fig. 3 - Dynamic Resistance vs. Zener Current

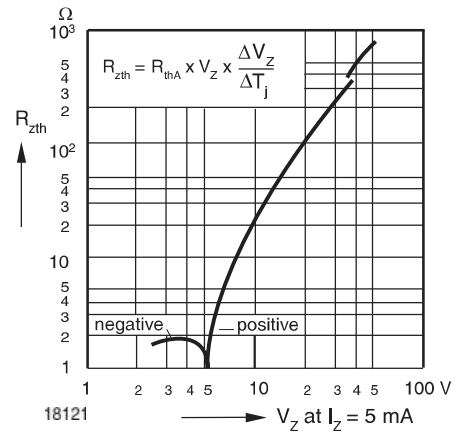


Fig. 6 - Thermal Differential Resistance vs. Zener Voltage

Typical Characteristics

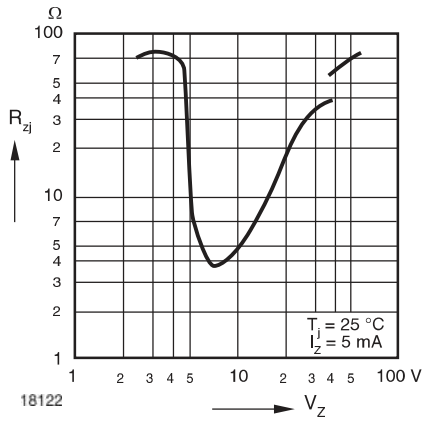


Fig. 7 - Dynamic Resistance vs. Zener Voltage

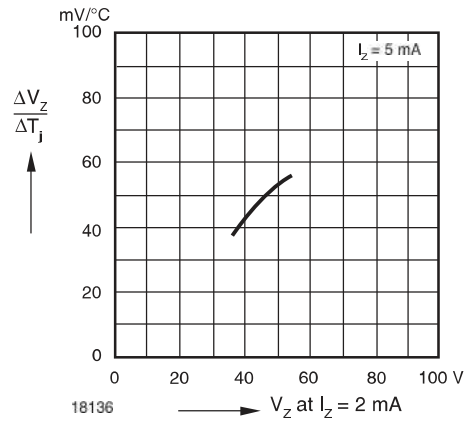


Fig. 10 - Temperature Dependence of Zener Voltage vs. Zener Voltage

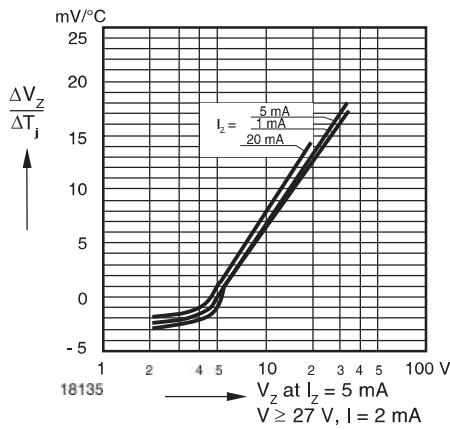


Fig. 8 - Temperature Dependence of Zener Voltage vs. Zener Voltage

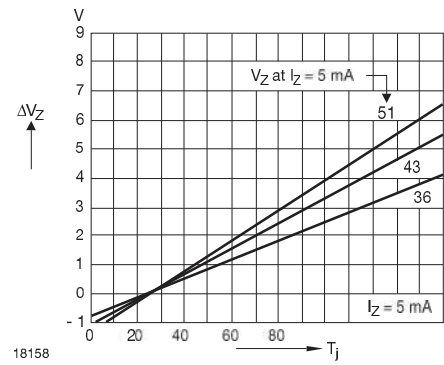


Fig. 11 - Change of Zener Voltage vs. Junction Temperature

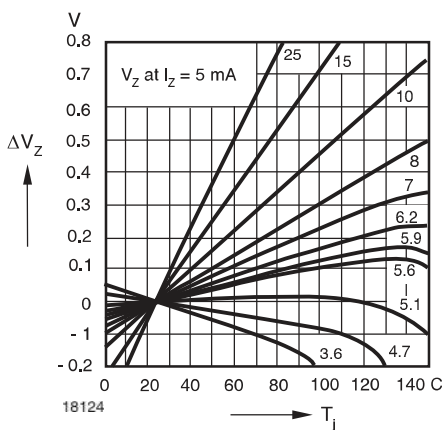


Fig. 9 - Change of Zener Voltage vs. Junction Temperature

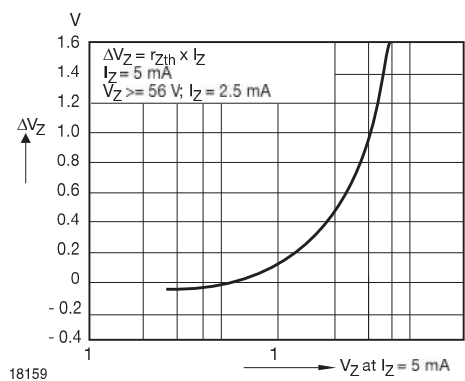


Fig. 12 - Change of Zener Voltage from Turn-on up to the Point of Thermal Equilibrium vs. Zener Voltage

Typical Characteristics

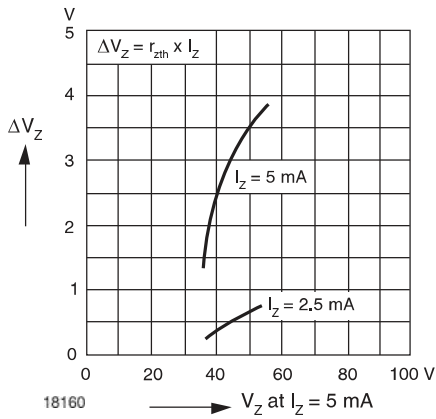


Fig. 13 - Change of Zener Voltage from Turn-on up to the Point of Thermal Equilibrium vs. Zener Voltage

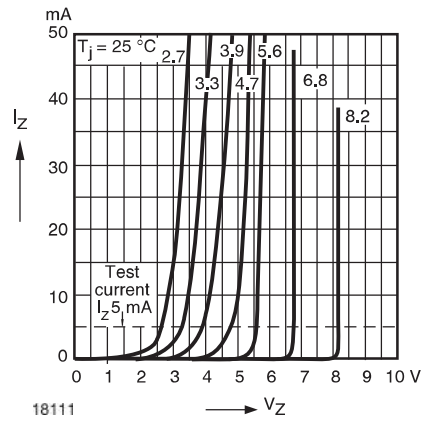


Fig. 14 - Breakdown Characteristics

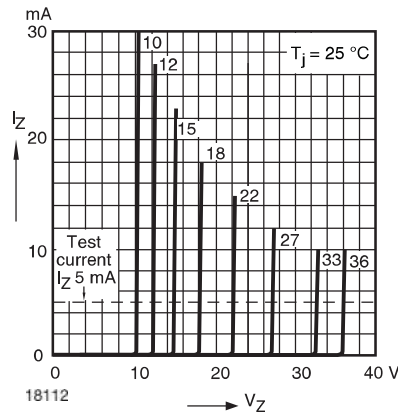


Fig. 15 - Breakdown Characteristics

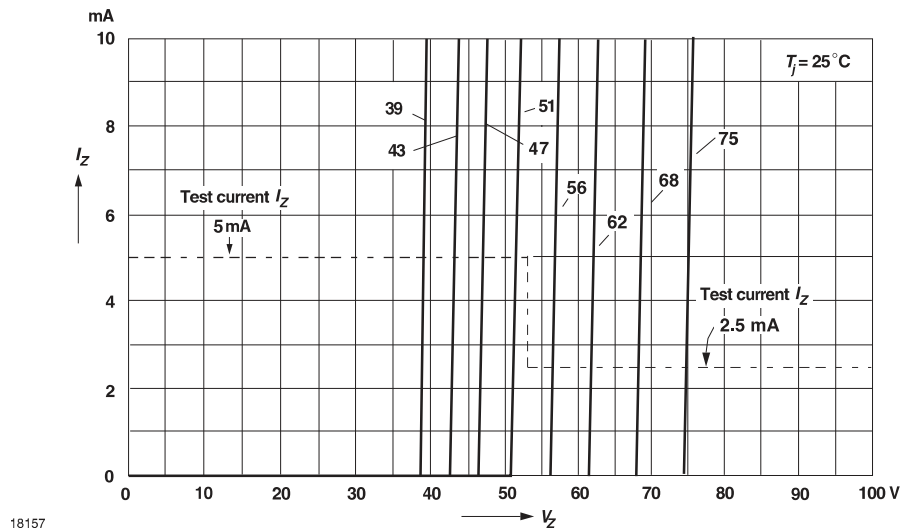
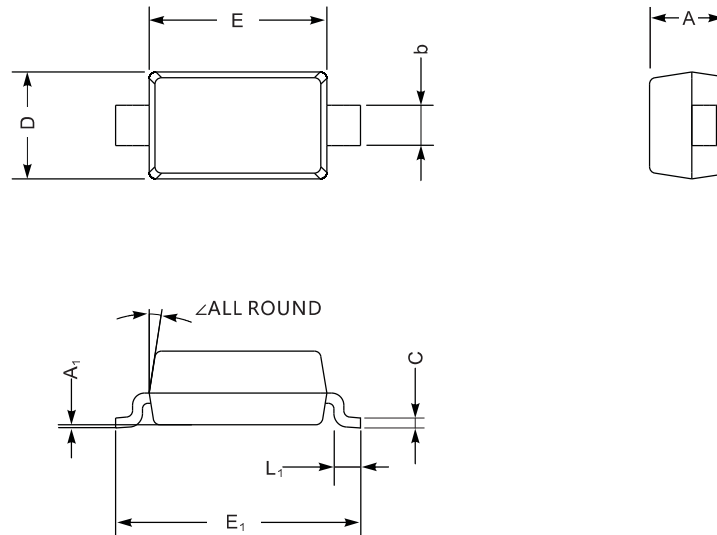


Fig. 16 - Breakdown Characteristics

The curve above is for reference only.

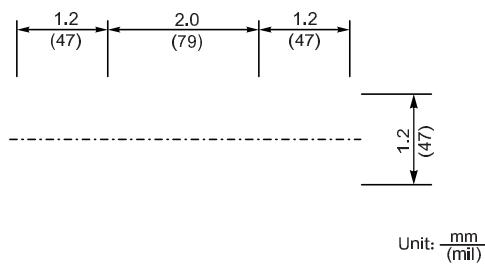
Package Outline SOD-123

Plastic surface mounted package; 2 leads



UNIT		A	C	D	E	E ₁	L ₁	b	A ₁	∠
mm	max	1.3	0.22	1.8	2.8	3.9	0.45	0.7	0.2	9°
	min	0.9	0.09	1.5	2.5	3.6	0.25	0.5	—	
mil	max	51	8.7	71	110	154	18	28	8	
	min	35	3.5	59	98	142	10	20	—	

The recommended mounting pad size



Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard
SOD-123	Tape/Reel, 7" reel	3000	EIA-481-1

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Zener Diodes](#) category:

Click to view products by [YFW Electronics](#) manufacturer:

Other Similar products are found below :

[RKZ13B2KG#P1](#) [DL5234B](#) [1N4682](#) [1N4693](#) [1N4732A](#) [1N4736A](#) [1N4750A](#) [1N4759ARL](#) [1N5241B](#) [1N5365B](#) [1N5369B](#) [1N747A](#)
[1N964B](#) [1N966B](#) [1N968B](#) [1N972B](#) [JANS1N4974US](#) [JANTX1N5907](#) [1N4692](#) [1N4702](#) [1N4704](#) [1N4711](#) [1N4714](#) [1N4745ARL](#)
[1N4752ARL](#) [1N4760ARL](#) [1N5221B](#) [1N5242BTR](#) [1N5350B](#) [1N5352B](#) [1N961BRR1](#) [1N964BRL](#) [RKZ5.1BKU#P6](#) [3SMAJ5946B-TP](#)
[3SMAJ5950B-TP](#) [MMSZ5230BQ-13-F](#) [MMSZ5232BQ-13-F](#) [BZX84C7V5](#) [3SMAJ5945B-TP](#) [3SMAJ5947B-TP](#) [3SMBJ5941B-TP](#)
[DZ2S240M0L](#) [SMAZ27-TP](#) [ZMM5224B-7](#) [RD16UM-T1-A](#) [RD10S-T1-A](#) [CDZT2R5.6B](#) [1N4762A G](#) [Z1SMA18](#) [JANTX1N4553B](#)